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#### FINAL REPORT - NOVEMBER 21, 1980

<u>Title:</u> "Semiconductor/Liquid Junctions: Molecular Manipulation of **Interface Energetics**"

Contract No.: N00014-78-C-0630

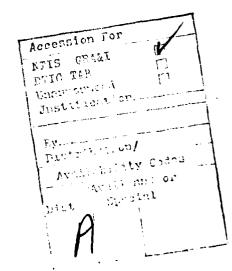
Project No.: NR 051-696

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Accomplishments (8-01-78 - 7-31-80, Contract No. N00014-78-C-0630)

Research carried out during the two year period 8-01-78 - 7-31-80 focused on n-type semiconducting photoanodes prepared from naturally occurring, single-crystal MoS<sub>2</sub> and synthetic single-crystal MoSe<sub>2</sub>. Work on \*textured\* single-crystal (100) Si was initiated under contract N00014-78-C-0630 and continued under contract N00014-75-C-0880, project no. NR 051-579. Additionally, preliminary study of TiO<sub>2</sub> and SrTiO<sub>3</sub> photoanode surfaces revealed interesting behavior that is being pursued under contract no. N00014-75-C-0880, project no. NR 051-579. The highlights of our accomplishments in these areas are given in the paragraphs below.

N-Type MoY<sub>2</sub>/Liquid Electrolyte Junctions. N-type MoS<sub>2</sub> and MoSe<sub>2</sub> have been characterized in CH<sub>3</sub>CN/0.10 M [n-Bu<sub>4</sub>N]ClO<sub>4</sub> electrolyte solutions containing various redox reagents. The use of CH<sub>3</sub>CN allows the examination of a wider range of redox reagents than is possible in H<sub>2</sub>O; we found that both n-type MoS<sub>2</sub> and MoSe<sub>2</sub> resist photoanodic decomposition in CH<sub>3</sub>CN compared to H<sub>2</sub>O. It would appear that the rationale rests in the fact that the energetics for photoanodic decomposition depend strongly on the solvation energy for the various products. The fact is that MoS<sub>2</sub> and MoSe<sub>2</sub> exhibit photoanodic decomposition in CH<sub>3</sub>CN/O.10 M [n-Bu<sub>4</sub>N]ClO<sub>4</sub> at a ~0.5 V more positive potential than in aqueous electrolyte. We discovered that MoS<sub>2</sub> and MoSe<sub>2</sub> photoanodes could be used to effect the uphill 2 Cl<sup>-</sup> + Cl<sub>2</sub> process, without destruction of the photoanode at a Cl<sup>-</sup> concentration where no Cl<sub>2</sub> is generated (only photoanodic decomposition of the electrode is observed) in aqueous solution.

Characterization of the interface energetics for  $MoS_2$  and  $MoSe_2$  was in fact the foundation for a study aimed at showing that surface modification could inhibit the effect of  $\Gamma$  adsorption in aqueous solution. The adsorption of  $\Gamma$  in aqueous solutions gives an ~0.5 V shift in the flat-band potential

for  ${\rm MoS}_2$  or  ${\rm MoSe}_2$ . Preliminary experiments showed that ferrocene-based redox reagents could be used to functionalize the surface of both photoanodes. Polymeric quantities of a ferrocene reagent could be anchored to the surface; the reduction of N,N'-dimethyl-4,4'-bipyridinium could be inhibited; but the behavior of I was not significantly affected. Such data suggest that the I , but not the N,N'-dimethyl-4,4'-bipyridinium reagent, could penetrate through the surface-confined polymer. These studies are continuing under contract no. NOOO14-75-C-0880, project no. NR 051-579.

Textured <100> Si/Liquid Electrolyte Junctions. Previous work established that <100> single-crystal Si can be chemically etched to reveal <111> planes resulting in a "textured" surface that has lower specular reflection and higher effective surface area than polished <100> Si. We initiated a study, completed under contract no. N00014-75-C-0630, project no. NR 571-696, to demonstrate that "textured" n-type Si can be exploited to improve performance of photoelectrochemical devices. Work on p-type Si shows that it too can be improved by the texturing procedure.

N-Type  $\mathrm{Ti0}_2$  and  $\mathrm{SrTi0}_3$  Surfaces. One of our initial objectives was to exhaustively functionalize an n-type semiconducting oxide surface to remove all sites of protonation/deprotonation equilibria. Both n-type  $\mathrm{Ti0}_2$  and  $\mathrm{SrTi0}_3$  have been successfully functionalized using a hydrolytically unstable ferrocene reagent that should react with the surface-OH groups. Part of the strategy in using the ferrocene-based reagent was that  $\mathrm{E}^\circ$ (ferricenium/ferrocene) is very close to the position of a postulated surface state of  $\mathrm{Ti0}_2$ . During the preliminary studies of  $\mathrm{Ti0}_2$  and  $\mathrm{SrTi0}_3$  in  $\mathrm{CH}_3\mathrm{CN/0.10}$  M [n-Bu4N]ClO4 we discovered two important facts: (i) the heterogeneous oxidation of ferrocene at illuminated n-type  $\mathrm{Ti0}_2$  or  $\mathrm{SrTi0}_3$  is exceedingly slow compared to the rate at n-type Si, GaAs,  $\mathrm{InP}$ ; (ii)  $\mathrm{Ti0}_2$  and  $\mathrm{SrTi0}_3$  appear to be "Fermi level pinned" when contacting liquid electrolyte solutions having  $\mathrm{E}_{\mathrm{redox}}$  more positive

than ~0.0 V vs. SCE. Both of these discoveries afford us a special opportunity to add to the understanding of interface energetics for these metal oxide semiconductors. The Fermi level pinning and slow photooxidation suggest a rather specific surface state distribution. This issue is being elaborated under contract no. NO0014-75-C-0880, project no. NR 051-579.

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Research Personnel (Contract No. N00014-78-C-0630)

Mark S. Wrighton, Professor of Chemistry, Principal Investigator

Lynn F. Schneemeyer, Ph.D., Postdoctoral Research Associate

James A. Bruce, Graduate Research Assistant

#### Technical Reports (Contract No. N00014-78-C-0630) (with Journal Reference)

- ONR-TR-1 "Flat-Band Potential of n-Type Semiconducting Molybdenum Disulfide by Cyclic Voltammetry of Two-Electron Reductants: Interface Energetics and the Sustained Photooxidation of Chloride", Lynn F. Schneemeyer and Mark S. Wrighton. (Published: <u>J. Am. Chem. Soc.</u>, 1979, 101, 6496.)
- ONR-TR-2 "Photoelectrochemical Conversion of Optical Energy to Electricity and Fuels", Mark S. Wrighton. (Published: Acc. Chem. Res., 1979, 12, 303.)
- ONR-TR-3 "N-Type Molybdenum Diselenide-Based Liquid Junction Solar Cells:
  A Non-Aqueous Electrolyte Syste- Employing the Chlorine/Chloride
  Couple", Lynn F. Schneemeyer, Mark S. Wrighton, Angelica Stacy,
  and Michell J. Sienko. (Published: Appl. Phys. Lett., 1980, 36, 701.)
- ONR-TR-4 "n-Type Molybdenum Diselenide-Based Photoelectrochemical Cells: Evidence for Fermi Level Pinning and Comparison of the Efficiency for Conversion of Light to Electricity with Various Solvent/Halogen/Halide Combinations", Lynn F. Schneemeyer and Mark S. Wrighton. (Published: J. Am. Chem. Soc., 1980, 102, 0000.)

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